



Spec No. :DS30-2002-148 Effective Date: 06/03/2017

Revision: B

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4



LED DISPLAY

LSHD-A103

Rev	<u>Description</u>	<u>By</u>	<u>Date</u>			
-						
Above data for PD and Customer tracking only						
-	New	Thomas Yu	12/31/2002			
Α	Update rev in system	Reo Lin	04/27/2011			
В	Update rev in system	Erin Cheng	05/26/2017			



1. Description

The LSHD-A103 is a 0.3 inch (7.62 mm) digit height single-digit display. This device uses AllnGaP RED LED chips (AllnGaP epi on GaAs substrate). The display has light gray face and white segments.

1.1 Features

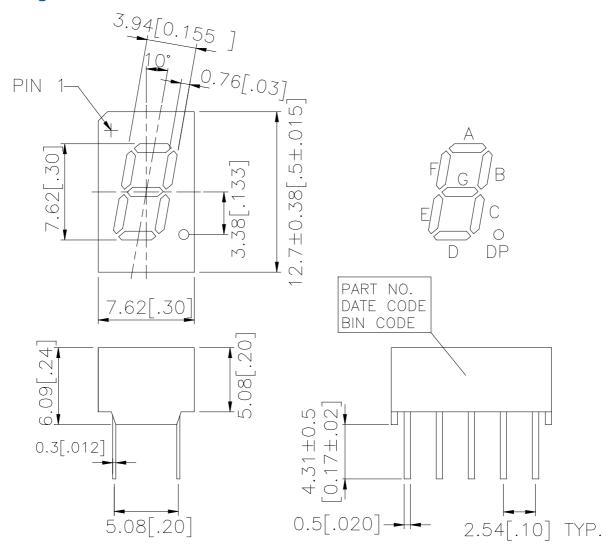
- 0.3 inch (7.62 mm) DIGIT HEIGHT
- CONTINUOUS UNIFORM SEGMENTS
- LOW POWER REQUIREMENT
- EXCELLENT CHARACTERS APPEARANCE
- HIGH BRIGHTNESS & HIGH CONTRAST
- WIDE VIEWING ANGLE
- SOLID STATE RELIABILITY
- CATEGORIZED FOR LUMINOUS INTENSITY.
- LEAD-FREE PACKAGE(ACCORDING TO ROHS)

1.2 Device

Part No	Description		
AllnGaP RED	Common Cathode		
LSHD-A103	Rt. Hand Decimal		



2. Package Dimensions

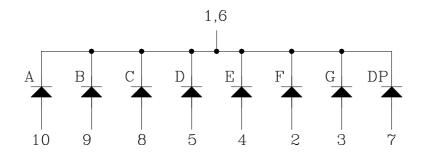


Notes:

- 1. All dimensions are in millimeters. Tolerances are ±0.25 mm (0.01") unless otherwise noted
- 2. Pin tip's shift tolerance is \pm 0.4 mm
- 3. Foreign material on segment ≤ 10 mil
- 4. Ink contamination (surface) \leq 20mils
- 5. Bubble in segment \leq 10mil
- 6. Bending \leq 1% of reflector length



3. Internal Circuit Diagram



4. Pin Connection

No	Connection			
1	Common Cathode			
2	Anode F			
3	Anode G			
4	Anode E			
5	Anode D			
6	Common Cathode			
7	Anode DP			
8	Anode C			
9	Anode B			
10	Anode A			



5. Rating and Characteristics

5.1. Absolute Maximum Rating at Ta=25℃

Unit			
mW			
mA			
mA			
nA/℃			
-35℃ to +105℃			
-35℃ to +105℃			
m,			

Solder Condition: 1/16 inch below seating plane for 3 seconds at 260° C or temperature of unit (during assembly) not over max. temperature rating above

5.2. Electrical / Optical Characteristics at Ta=25℃

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Test Condition
Average Luminous Intensity Per Segment	IV	200	692		μcd	IF=1mA IF=10mA
Average Luminous intensity Fer Segment		3400	9000			
Peak Emission Wavelength	λр		650		nm	IF=20mA
Spectral Line Half-Width	Δλ		20		nm	IF=20mA
Dominant Wavelength	λd		639		nm	IF=20mA
Forward Voltage Per Chip	VF		2.1	2.6	V	IF=20mA
Reverse Current Per Segment(*2)	IR			100	μΑ	VR=5V
Luminous Intensity Matching Ratio (Similar Light Area)	IV-m			2:1		IF=10mA

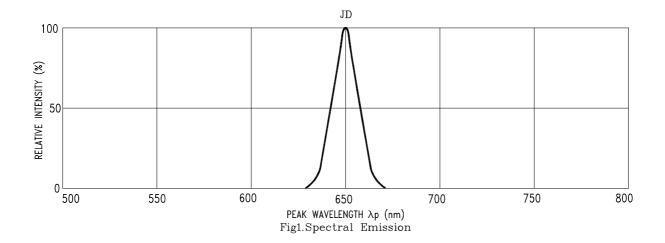
Notes:

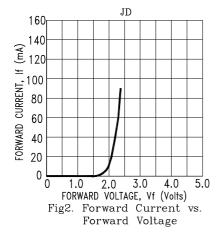
- 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commission International De L'Eclariage) eye-response curve
- 2. Reverse voltage is only for IR test. It cannot continue to operate at this situation

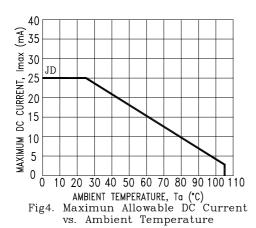


5.4. Typical Electrical / Optical Characteristics Curves

(25℃ Ambient Temperature Unless Otherwise Noted)







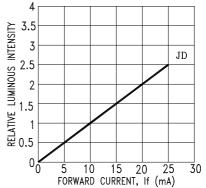


Fig3. Relative Luminous Intensity vs. DC Forward Current

